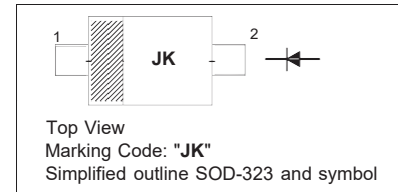


BAT46WH SIGNAL SCHOTTKY BARRIER DIODE**Features**

- Low Forward Voltage drop
- Surface mount device
- Reverse voltage $V_R \leq 100$ V
- Low capacitance

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

**Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)**

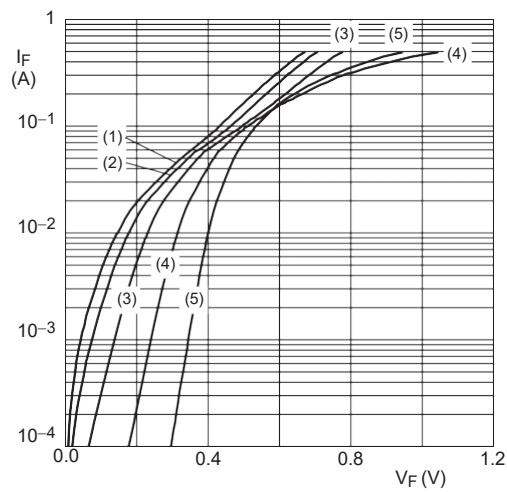
Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Continuous Forward Current	I_F	250	mA
Power Dissipation	P_{tot}	400	mW
Thermal Resistance Junction Ambient	R_{thJA}	312	$^\circ\text{C/W}$
Operating Junction Temperature Range	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 100 \mu\text{A}$	V_{BR}	100	-	-	V
Forward Voltage at $I_F = 0.1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 250 \text{ mA}$	V_F	- - -	- - -	0.20 0.35 0.85	V
Reverse Current at $V_R = 1.5 \text{ V}$ at $V_R = 10 \text{ V}$ at $V_R = 50 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 1.5 \text{ V}$, $T_j = 60^\circ\text{C}$ at $V_R = 10 \text{ V}$, $T_j = 60^\circ\text{C}$ at $V_R = 50 \text{ V}$, $T_j = 60^\circ\text{C}$ at $V_R = 75 \text{ V}$, $T_j = 60^\circ\text{C}$	I_R	- - - - - - - -	- - - - - - - -	0.5 0.8 2 4 12 20 44 80	μA
Total Capacitance at $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$ at $V_R = 1 \text{ V}$, $f = 1 \text{ MHz}$	C_T	- -	- -	39 21	pF

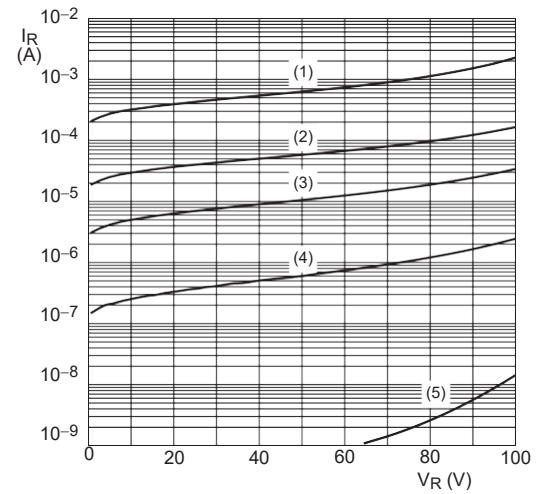
Note: 1. Part mounted on FR-4 board with recommended pad layout, which can be found on ourwebsite
2. Short duration test pulse used to minimize self-heating effect

Typical Characteristics



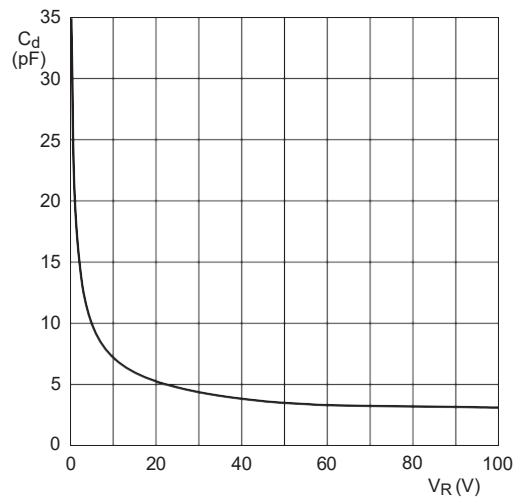
- (1) $T_{amb} = 150\text{ }^{\circ}\text{C}$
- (2) $T_{amb} = 125\text{ }^{\circ}\text{C}$
- (3) $T_{amb} = 85\text{ }^{\circ}\text{C}$
- (4) $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (5) $T_{amb} = -40\text{ }^{\circ}\text{C}$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}$
- (3) $T_{amb} = 60\text{ }^{\circ}\text{C}$
- (4) $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (5) $T_{amb} = -40\text{ }^{\circ}\text{C}$

Fig 2. Reverse current as a function of reverse voltage; typical values



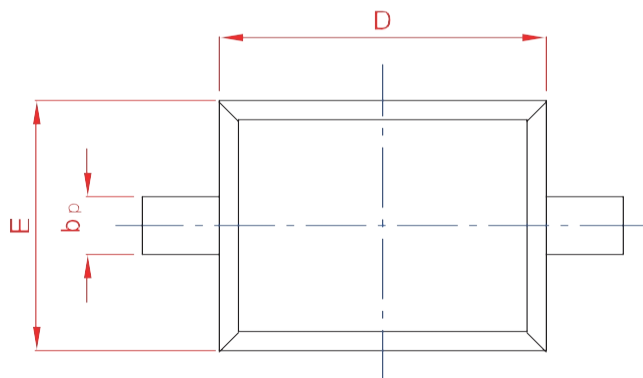
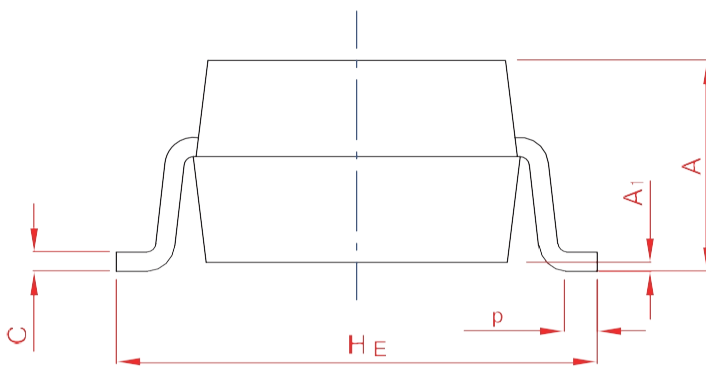
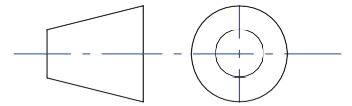
$f = 1\text{ MHz}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b _p	C	D	E	H _E	A ₁	L _p
mm	1.20 0.90	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30	0.10 0.01	0.50 0.20